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April 1st, 2010 Renesas Electronics Corporation

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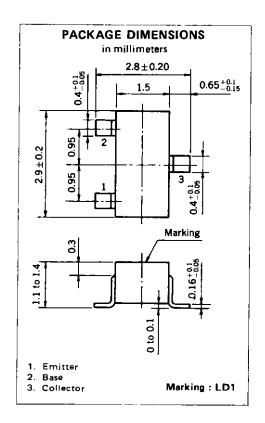
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SILICON TRANSISTOR FA3L4Z

KEY MATRIX CONNECTION SWITCHING DIODE AND RESISTOR BUILT-IN TYPE NPN TRANSISTOR MINI MOLD

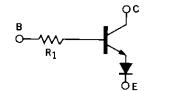


DESCRIPTION

The FA3L4Z is Diode and Resistor Built-in type transistor designed for transistor switch of Key Matrix Connection.

FEATURES

Built-in Diode block reverse current



 $R_1 = 47 \text{ k}\Omega$

Complementary to FN3L4Z

ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Current $(T_a = 2)$	25 °C)		
Collector to Base Voltage	V_{CBO}	20	٧
Collector to Emitter Voltage	V_{CEO}	20	V
Emitter to Base Voltage	V_{EBO}	5	V
Collector Current (DC)	Ic	20	mΑ
Reverse Voltage (Diode)	V _R	6	٧
Maximum Power Dissipation			
Total Power Dissipation			
at 25 °C Ambient Temperature	P _T	200	mW
Maximum Temperatures			
Junction Temperature	T_{j}	150	°C
Storage Temperature Range	T_{stg}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	СВО			100	nΑ	V _{CB} = 20 V, I _E = 0
Diode Reverse Current	IECX			1.0	μА	V _I = 5 V, V _{EC} = 5.5 V
DC Current Gain	hFE*	30	120			V _{CE} = 5.0 V, I _C = 1.0 mA
Collector Saturation Voltage	VCE(sat)1		0.8	1.0	v	I _C = 0.1 mA, I _B = 0.01 mA
Collector Saturation Voltage	V _{CE(sat)2} *		1.0	1.2	V	I _C = 1.0 mA, I _B = 0.1 mA
Input Resistor	R ₁	32.9	47.0	61.1	kΩ	

^{*} Pulsed : PW \leq 350 μ s, Duty Cycle \leq 2 %

TYPICAL CHARACTERISTICS (Ta = 25 °C)

